# International Rectifier

## 40HF(R) SERIES

#### STANDARD RECOVERY DIODES

Stud Version

#### Features

- High surge current capability
- Stud cathode and stud anode version
- Leaded version available
- Types up to 1600V V<sub>RRM</sub>

40 A

#### Typical Applications

- Battery charges
- Converters
- Power supplies
- Machine tool controls
- Welding

#### Major Ratings and Characteristics

Parameters		40H	Llaita	
		10 to 120	140, 160	Units
I <sub>F(AV)</sub>		40	40	А
	@ T <sub>C</sub>	140	110	°C
I <sub>F(RMS)</sub>		6	А	
I <sub>FSM</sub>	@50Hz	5	Α	
	@ 60Hz	59	95	Α
l <sup>2</sup> t	@50Hz	16	A <sup>2</sup> s	
	@ 60Hz	14	A <sup>2</sup> s	
V <sub>RRM</sub>	range	100 to 1200	1400, 1600	V
T <sub>J</sub>	range	- 65 to 190	- 65 to 160	°C



#### **ELECTRICAL SPECIFICATIONS**

#### Voltage Ratings

Type number	Voltage Code	V <sub>RRM</sub> , maximum repetitive peak reverse voltage V	V <sub>RSM</sub> , maximum non- repetitive peak reverse voltage V	I <sub>RRM</sub> max. @ T <sub>J</sub> = T <sub>J</sub> max. mA
	10	100	200	9
	20	200	300	
	40	400	500	
40HF(R)	60	600	700	
	80	800	900	
	100	1000	1100	
	120	1200	1300	
	140	1400	1500	4.5
	160	1600	1700	

#### **Forward Conduction**

Parameter		40HF(R)		Units	Conditions		
		10 to 120	140,160	UIIIIS	Conditions		
I <sub>F(AV)</sub> Max. average forward current		40	40	Α	180° conduction, half sine wave		wave
@ Case temperature		140	110	°C			
I <sub>F(RMS)</sub>	Max. RMS forward current	6	2	Α			
I <sub>FSM</sub>	Max. peak, one-cycle forward,				t = 10ms	No voltage	
	non-repetitive surge current				t = 8.3ms	reapplied	
					t = 10ms	100% V <sub>RRM</sub>	
		500			t = 8.3ms	reapplied	Sinusoidal half wave,
I²t	Maximum I2t for fusing	16	00	A <sup>2</sup> s	t = 10ms	No voltage	Initial $T_j = T_j \text{ max.}$
			1450		t = 8.3ms	reapplied	
			1150		t = 10ms	100% V <sub>RRM</sub>	
			1050		t = 8.3ms	reapplied	
I²√t	Maximum I <sup>2</sup> √t for fusing	16000		A²√s	t = 0.1 to 10ms, no voltage reapplied		
V <sub>F(TO)</sub>	Value of threshold	0.65		.,			
( - /	voltage (up to 1200V)			V	$T_J = T_J max$		
V <sub>F(TO)</sub>	Value of threshold	0.76					
, -,	voltage (for 1400V, 1600V)				$T_J = T_J \text{ max.}$		
r <sub>f</sub>	Value of forward slope						
	resistance (up to 1200V) 4.29		mΩ	I <sub>J</sub> = I <sub>J</sub> max	$T_J = T_J \text{ max.}$		
r <sub>f</sub>	r <sub>f</sub> Value of forward slope		3.8		T T		
	resistance (for 1400V, 1600V)	3	.δ		$T_J = T_J \text{ max.}$		
V <sub>FM</sub>	Max. forward voltage drop	1.30 1.50 V I <sub>pk</sub> = 125A, T <sub>J</sub> = 25°C, t <sub>p</sub> = 400μs rec			400µs rectangular wave		

#### Thermal and Mechanical Specifications

	·				
Parameter		40HF(R)		1.1	0 177
		10 to 120	140 to 160	Units	Conditions
T <sub>J</sub>	Max. junction operating temperature range	-65 to 190	-65 to 160		
T <sub>stg</sub>	Max. storage temperature range	-65 to 190	-65 to 160	°C	
R <sub>thJC</sub>	Max. thermal resistance, junction to case	0.95			DC operation
R <sub>thCS</sub>	Max. thermal resistance, case	0.	25	K/W	Mounting surface, smooth, flat and
	to heatsink	0.25			greased
Т	Max. allowed mounting torque ±10%	2.3-3.4		Nm	Not lubricated threads
		20-30		lbf•in	
wt	Approximate weight	17 (0.6)		g (oz)	unleaded device
	Case style	DO-203AB (DO5)			See Outline Table

### $\Delta R_{\text{thJC}}$ Conduction

(The following table shows the increment of thermal resistence  $R_{th,C}$  when devices operate at different conduction angles than DC)

		8100		
Conduction angle	Sinusoidal conduction	Rectangular conduction	Units	Conditions
180°	0.14	0.10		$T_J = T_J \text{ max.}$
120°	0.16	0.17		
90°	0.21	0.22	K/W	
60°	0.30	0.31		
30°	0.50	0.50		

#### Ordering Information Table



1 - 40 = Standard device

41 = Not isolated lead

42 = Isolated lead with silicone sleeve

(Red = Reverse polarity)

(Blue = Normal polarity)

2 - Standard diode

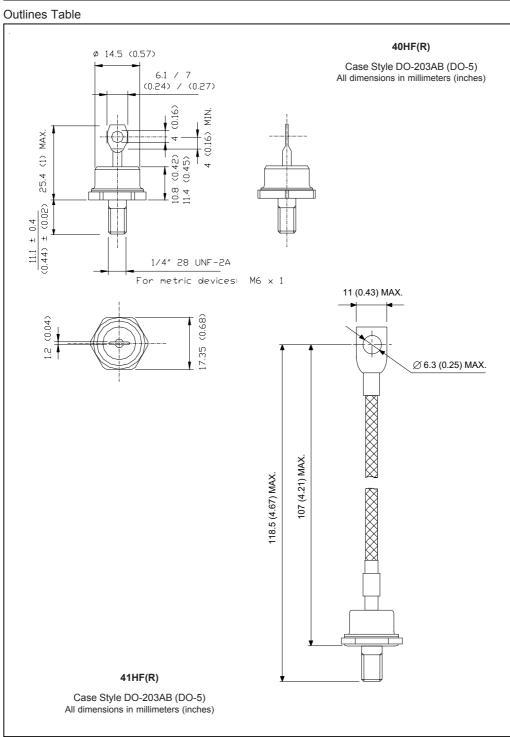
3 - None = Stud Normal Polarity (Cathode to Stud)

R = Stud Reverse Polarity (Anode to Stud)

Voltage code: Code x 10 = V<sub>RRM</sub> (See Voltage Ratings table)

5 - None = Stud base DO-203AB (DO-5) 1/4" 28UNF-2A

M = Stud base DO-203AB (DO-5) M6 X 1



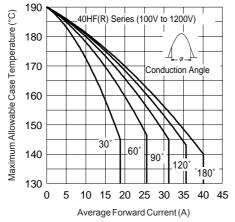


Fig. 1 - Current Ratings Characteristics

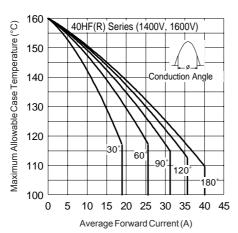


Fig. 3 - Current Ratings Characteristics

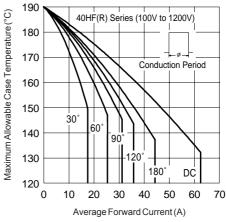


Fig. 2 - Current Ratings Characteristics

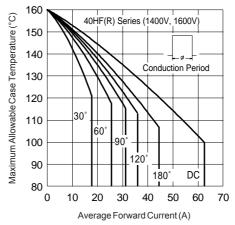


Fig. 4 - Current Ratings Characteristics

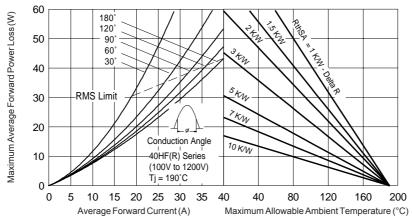


Fig. 5 - Forward Power Loss Characteristics

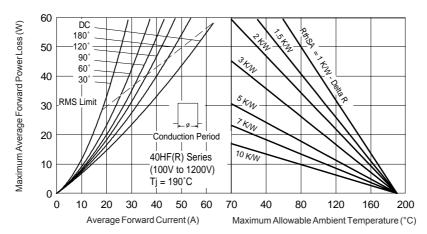


Fig. 6 - Forward Power Loss Characteristics

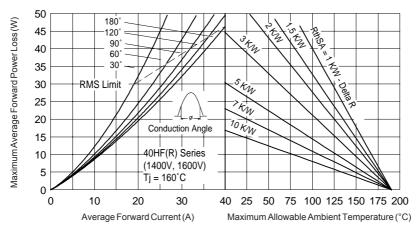


Fig. 7 - Forward Power Loss Characteristics

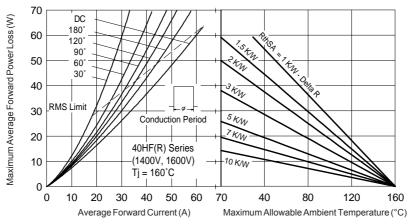
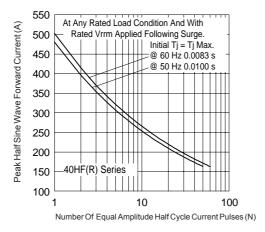


Fig. 8 - Forward Power Loss Characteristics



 $Fig.\,9-Maximum\,Non-Repetitive\,Surge\,Current$ 

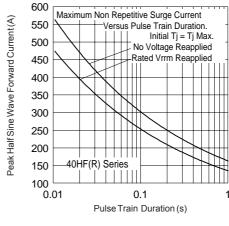


Fig. 10 - Maximum Non-Repetitive Surge Current

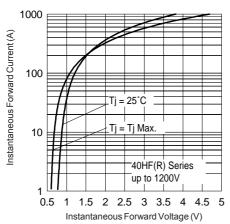


Fig. 11 - Forward Voltage Drop Characteristics (up to 1200V)

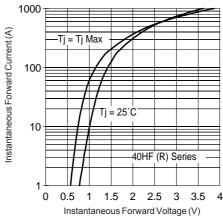


Fig. 12 - Forward Voltage Drop Characteristics (for 1400V, 1600V)

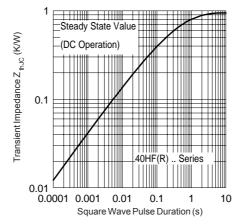


Fig. 13 - Thermal Impedance  $Z_{thJC}$  Characteristics

Data and specifications subject to change without notice. This product has been designed and qualified for Industrial Level.

Qualification Standards can be found on IR's Web site.



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